DISCRETE SEMICONDUCTORS



Product specification

September 2018



Rectifier diodes ultrafast

FEATURES

- · Low forward volt drop
- · Fast switching
- Soft recovery characteristic
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

GENERAL DESCRIPTION

Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYR29 series is supplied in the conventional leaded SOD59 conventional (TO220AC) package.

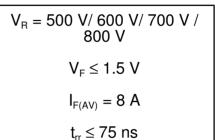
SYMBOL



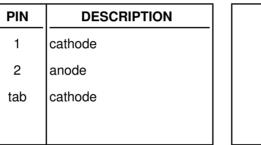
BYR29 series

Product specification

QUICK REFERENCE DATA



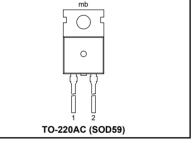
PINNING



k − K− a

001aaa020

SOD59 (TO220AC)



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT	
		BYR29		-500	-600	-700	-800	
V _{RRM}	Peak repetitive reverse voltage		-	500	600	700	800	V
V _{RWM}	Crest working reverse voltage		-	500	600	700	800	V
V _R	Continuous reverse voltage		-	500	600	700	800	V
$I_{F(AV)}$	Average forward current ¹	square wave; $\delta = 0.5$;	-		8	8		A
I _{FRM}	Repetitive peak forward current	T _{mb} ≤ 115 °C t = 25 μs; δ = 0.5; T _{mb} ≤ 115 °C	-		1	6		А
I _{FSM}	Non-repetitive peak forward current	t = 10 ms t = 8.3 ms sinusoidal; with	-			60 66		A A
T _{stg} T _i	Storage temperature Operating junction temperature	reapplied $V_{\text{RRM}(\text{max})}$	-40 -			50 50		Ĵ, Ĵ

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to mounting base	in free eir	-	-	2.5	K/W
R _{th j-a}	Thermal resistance junction to ambient	in free air.	-	60	-	K/W

¹ Neglecting switching and reverse current losses

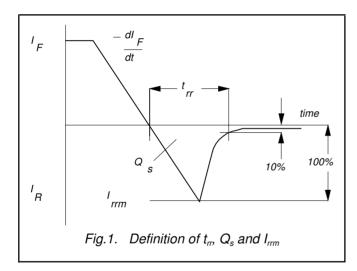
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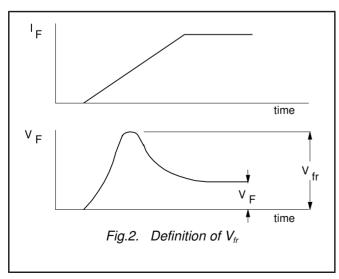
BYR29 series

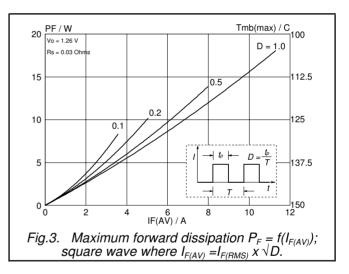
ELECTRICAL CHARACTERISTICS

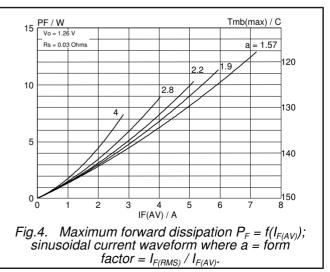
 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	Forward voltage	$I_F = 8 A; T_j = 150^{\circ}C$	-	1.07	1.50	V
I _R	Reverse current	$I_F = 20 \text{ A}$ $V_B = V_{BBM}$	-	1.75 1.0	1.95 10	ν μA
Qs	Reverse recovery charge	$V_R = V_{RRM}$; $T_j = 100 \degree C$ $I_F = 2 \ A \ to \ V_R \ge 30 \ V$;	-	0.1 150	0.2 200	mA nC
t _{rr}	Reverse recovery time	$dI_F/dt = 20 A/\mu s$ $I_F = 1 A to V_B \ge 30 V;$	-	60	75	ns
l _{rrm}	Peak reverse recovery current	$dI_F/dt = 100 \text{ A}/\mu s$ $I_F = 10 \text{ A to } V_R \ge 30 \text{ V};$	-	-	6	А
V _{fr}	Forward recovery voltage	dI _F /dt = 50 A/μs; T _j = 100 °C I _F = 10 A; dI _F /dt = 10 A/μs	-	5.0	-	V





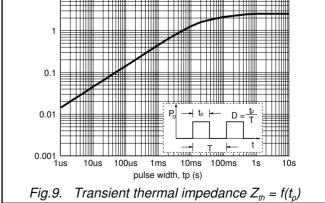




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trr / ns IF / A 1000 30 Tj = 25 C IF=10 A Tj = 150 C 25 1A4 100 20 15 max ' typ 10 10 _Tj = 25 C _Tj = 100 C 5 0 ∟ 0 1 1.5 VF / V 10 dIF/dt (A/us) 100 0.5 2 2.5 3 Fig.7. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j Fig.5. Maximum t_{rr} at $T_i = 25^{\circ}C$ and $100^{\circ}C$. Qs / nC Irrm / A 1000 10 -10/IF = 104 1 21 IF=1A 100 0.1 Tj = 25 C Tj = 100 C 0.01 10 10 -dIF/dt (A/us) 100 1.0 10 -dIF/dt (A/us) 100 Fig.6. Maximum I_{rrm} at $T_j = 25^{\circ}C$ and $100^{\circ}C$. Fig.8. Maximum Q_s at $T_i = 25^{\circ}C$ Transient thermal impedance, Zth j-mb (K/W) 10 1



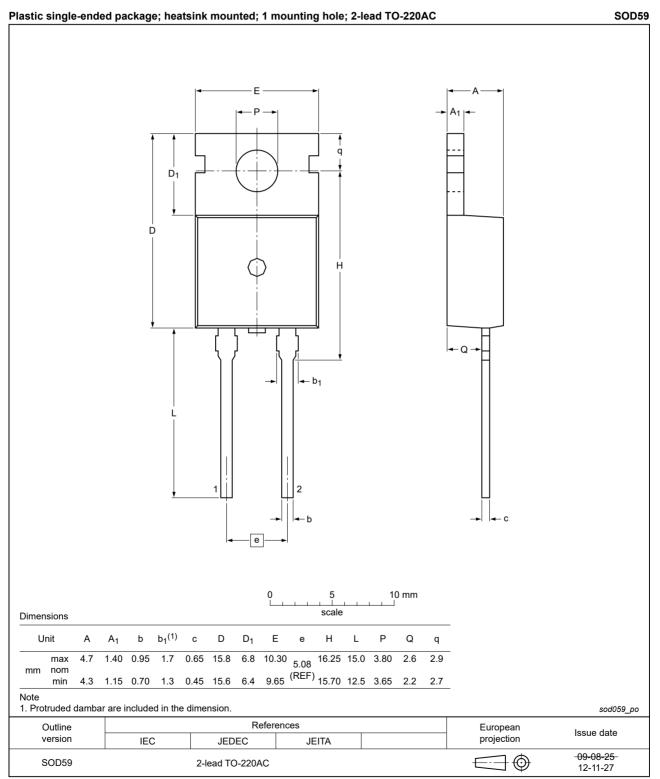


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MECHANICAL DATA



Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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